

100mA Single Inductor - Dual Output Power Supply

Features

- 2.7V to 5.5V Input Voltage
- Dual Regulated Output Using Single Inductor
- Positive Output Voltage Range:
 4.0V to 6.0V (100mV/Step)
- Negative Output Voltage Range:
 -6.0V to -4.0V (100mV/Step)
- Maximum Output Current: 100mA
- Outstanding Combined Efficiency
 η > 80% at I_{OUT} > 10 mA
 η > 85% at I_{OUT} > 40 mA
- Outstanding Transient Response & Line Regulation
- ±1.5% Output Voltage Accuracy
- Shut-Down Supply Current: 1uA
- Under-Voltage Lock-Out and Thermal Shutdown
- WLCSP 1.27mm×2.00mm×0.625mm-15B, 0.4mm Pitch Package

Applications

TFT LCD Smartphones, Tablets and NB Dual Power Supply Application

Typical Application Circuit

General Description

The AW37501 is designed to support positive /negative supply for driving TFT-LCD panels mainly in smartphones and tablets. The device employs a single inductor scheme to provide a small bill-of-material and smallest PCB solution size.

It integrates a step-up DC-DC converter for preceding supply. An architecture with LDO and negative charge pump (NCP) generates dual outputs at +5.4V (default) and -5.4V (default), whose voltages can be programmed via an I²C compatible interface.

The device offers excellent line and load regulation performances, as well as load transient. It features an outstanding efficiency that is greater than 80% when I_{OUT}>10mA and 85% when I_{OUT}>40mA. With its input voltage range of 2.7V to 5.5V, it can be powered by single-cell batteries (Li-Ion, Ni-Li, Li-Polymer).

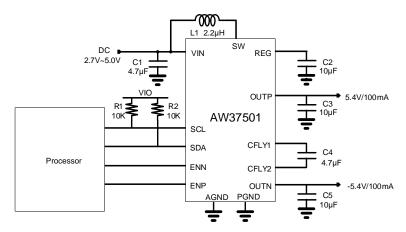


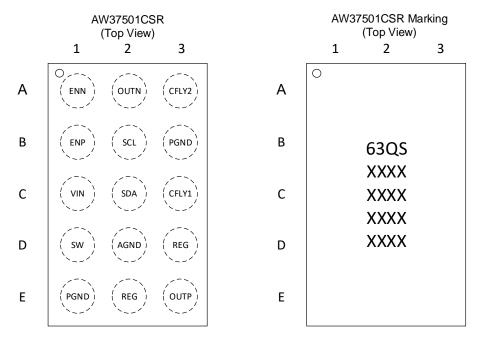
Figure 1 Typical Application Circuit of AW37501

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Pin Configuration And Top Mark



63QS - AW37501CSR Marking XXXX XXXX XXXX XXXX- Production Tracing Code

Figure 2 Pin Configuration and Top Mark

Pin Definition

No.	NAME	DESCRIPTION
A1	ENN	Enable input for negative output (OUTN). A logic high enables the negative output, a logic low forces the output into shutdown.
A2	OUTN	Output pin of the negative charge pump.
А3	CFLY2	Negative charge pump flying capacitor pin.
B1	ENP	Enable Input for positive output (OUTP). A logic high enables the positive output, a logic low forces the output into shutdown.
B2	SCL	Clock input for the I ² C serial interface.
В3	PGND	Power Ground.
C1	VIN	Power Input.
C2	SDA	Data input for the I ² C serial interface.
C3	CFLY1	Negative charge pump flying capacitor pin.
D1	SW	Switch pin of the boost converter.
D2	AGND	Analog ground.
D3	REG	Boost converter output pin.
E1	PGND	Power Ground.
E2	REG	Boost converter output pin.
E3	OUTP	Output pin of the LDO.

Functional Block Diagram

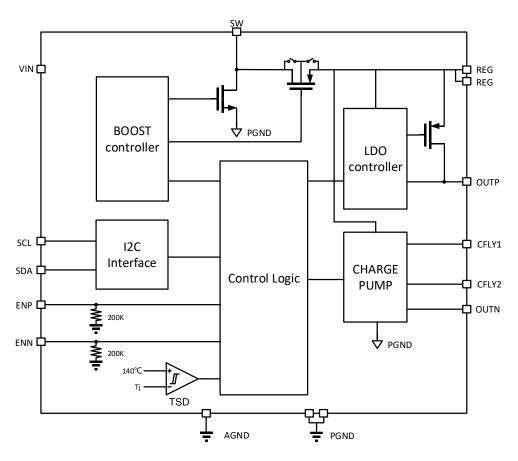


Figure 3 Functional Block Diagram



Typical Application Circuits

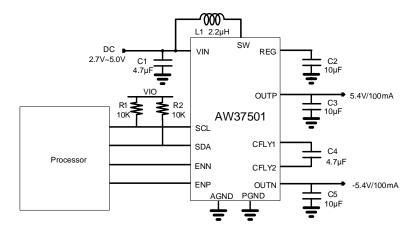


Figure 4 AW37501 Application circuit

Notice for typical application circuits:

- 1. All peripheral devices should be as closed as possible to the chip, C1、C2、C3、C4、C5 and L1 should be closed to VIN、REG、OUTP、CFLY1/2 and OUTN pins respectively. Besides the metal traces between them should be short and wide.
- 2. The inductor recommended 2.2μH is suitable for 80mA and 100mA application for better efficiency, but the value is usually 4.7μH for good current sensing and controlling function inside in 40mA mode.
- 3. The input capacitor C1 can be larger values; the output capacitors C2, C3 and C5 should be selected in recommended values, the larger value of C2, C3 and C5, the smaller of the ripple voltage, but the longer of starting time; the flying capacitor C4 can be larger, but overlarge value may cause large inrush current during startup.

Ordering Information

Part Number	Temperature	Package	Marking	Moisture Sensitivity Level	Environmental Information	Delivery Form
AW37501CSR	-40°C∼85°C	WLCSP 1.27mmX2.00mm X0.625mm-15B	63QS	MSL1	ROHS+HF	3000 units/ Tape and Reel



Absolute Maximum Ratings(NOTE1)

PARAMETER	PARAMETERS			
Supply voltage rar	Supply voltage range V _{IN}			
Input voltage range	ENN, ENP, SDA, SCL	-0.3V to V _{IN} +0.3V		
	SW	-0.3V to 8V		
Outrot with a series	REG, CFLY1	-0.3V to 8V		
Output voltage range	OUTP	-0.3V to 7V		
	CFLY2, OUTN	-7V to 0.3V		
Junction-to-ambient therma	al resistance θ _{JA}	91.5°C/W		
Operating free-air temper	erature range	-40°C to 85°C		
Maximum operating junction	Maximum operating junction temperature T _{JMAX}			
Storage temperatur	Storage temperature T _{STG}			
Lead temperature (soldering	Lead temperature (soldering 10 seconds)			

NOTE1: Conditions out of those ranges listed in "absolute maximum ratings" may cause permanent damages to the device. In spite of the limits above, functional operation conditions of the device should within the ranges listed in "recommended operating conditions". Exposure to absolute-maximum-rated conditions for prolonged periods may affect device reliability.

ESD Rating and Latch Up

PARAMETERS	VALUE	UNIT
HBM (Human Body Model) (NOTE 2)	±2	kV
CDM ^(NOTE 3)	±1.5	kV
Latch-Up ^(NOTE 4)	+IT: 200; -IT: -200	mA

NOTE2: The human body model is a 100pF capacitor discharged through a 1.5k Ω resistor into each pin. Test

method: ESDA/JEDEC JS-001-2017

NOTE3: Test method: ESDA/JEDEC JS-002-2018

NOTE4: Test method: JESD78E

Recommended Components List

Component	DESCRIPTION	MIN.	TYP.	MAX.	UNIT
L1	Inductor		2.2		μΗ
C1	Input capacitor	4.7			μF
C2	REG output capacitor	4.7			μF
C4	Flying capacitor	2.2			μF
C3 & C5	OUTP and OUTN output capacitor	4.7			μF



Electrical Characteristics

V_{IN}=3.7V, ENN=ENP=V_{IN}, V_{OUTP}=5.4V, V_{OUTN}=-5.4V, T_A=25°C for typical values (unless otherwise noted)

	PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
INPUT VO	OLTAGES and CURRENTS					
V _{IN}	VIN supply voltage range		2.7		5.0	V
V _{UVLO}	Linder veltage leekeut threehold	V _{IN} rising	2.3	2.4	2.5	V
VUVLO	Under-voltage lockout threshold	V _{IN} falling	2.1	2.2	2.3	V
IQ	Quiescent current	I _{OUT} =0mA	0.6	0.83	1.2	mA
I _{SD}	Shutdown down current	ENP=ENN=0V		1	2	μΑ
LOGIC E	NN, ENP, SDA, SCL	1			1	
V _{IH}	High level input voltage	V _{IN} =2.5 V to 5.0 V	1.2			V
V_{IL}	Low level input voltage	VIIN 2.0 V to 0.0 V			0.4	V
VoL	Low level output voltage	V _{IN} =2.5 V to 5.0 V, sinking 2mA			0.4	V
R _{EN}	Pulldown resistors	ENP and ENN pull- down resistance	0.1	0.2	0.3	МΩ
BOOST C	CONVERTER CHARACTERISTICS					
ILIM	Boost converter valley current limit value		1.2	1.5	2.0	Α
Fsw	Boost converter switching frequency		1.1	1.4	1.7	MHz
T _{SS}	Soft start-up time			0.2	1.0	ms
LDO CHA	ARACTERISTICS					
	Positive output voltage range	In 100mV steps, no load	4.0		6.0	V
V_{OUTP}	Default output voltage	I _{OUTP} =80mA		5.4		V
	Positive output voltage accuracy	I _{OUTP} <100mA	-1.5		1.5	%
loutp	Positive output current capability	ENP=High	200			mA
		REG04H[4]=0	300	370	440	mA
OUTP_LIM	OUTP output current limit value	REG04H[4]=1	220	270	360	mA
V _{DROP}	Dropout voltage	V _{REG} =V _{OUTP} =5.4V, I _{OUTP} =150mA	30	60	100	mV
	OUTP line regulation	V _{IN} =2.7V to 5.0V,		0.024	0.08	%/V
V_{LIP}	OUTP line variation	I _{OUTP} =80mA		3	10	mV
V _{LOP}	OUTP load regulation	Δ I _{OUTP} =80mA		2	3	%/A
R _{DISP}	OUTP discharge resistor		40	60	100	Ω
NEGATIV	'E CHARGE PUMP CHARACTERIS	TICS	1	1	1	
Voutn	Negative output voltage range	In 100mV steps, no load	-6.0		-4.0	V
OUTN	Default Output	I _{OUTN} =80mA		-5.4		V
	<u> </u>	1	1	1	1	



	PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
	Negative output voltage accuracy	I _{OUTN} <100mA	-1.5		1.5	%
Іоити		REG03H[7:6]=00 , 40mA mode	40		60	mA
	Negative output current capability	REG03H[7:6]=01 , 80mA mode(default)	80		120	mA
		REG03H[7:6]=10 , 100mA mode	100		165	mA
F _{NCP}	Negative charge pump switching frequency		0.9	1.0	1.1	MHz
V _{LIN}	OUTN line regulation	V _{IN} =2.7V to 5.0V,		0.024	0.16	%/V
VLIN	OUTN line variation	I _{OUTN} =80mA		3	20	mV
V _{LON}	OUTN load regulation	ΔΙ _{ΟυτΝ} =100mA		8		%/A
Rdisn	OUTN discharge resistor		14	20	30	Ω
PROTEC	TION	,				
Тотр	Overheating shutdown temperature			140		°C
	Thermal hysteresis for Totp			20		°C

I²C INTERFACE TIMING

SYMBOL	DESCRIPTION	MIN	TYP	MAX	UNIT	
F _{SCL}	Interface Clock Frequency				400	kHz
4	Doglitah Timo	SCL		83		ns
t _{DEGLITCH}	Deglitch Time	SDA		115		ns
t _{HD:STA}	(Repeat-Start) Start Condition Hold Ti	me	0.6			μs
t _{LOW}	Low Level Width of SCL		1.3			μs
t _{HIGH}	High Level Width of SCL	0.6			μs	
tsu:sta	(Repeat-Start) Start Condition Setup	Гime	0.6			μs
t _{HD:DAT}	Data Hold Time		0			μs
tsu:dat	Data Setup Time		0.1			μs
t _R	Rising Time of SDA and SCL				0.3	μs
t _F	Falling Time of SDA and SCL			0.3	μs	
tsu:sto	Stop Condition Setup Time	0.6			μs	
tBUF	Time Between Start and Stop Condition	on	1.3			μs

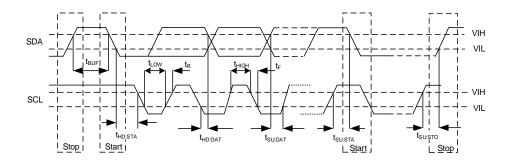
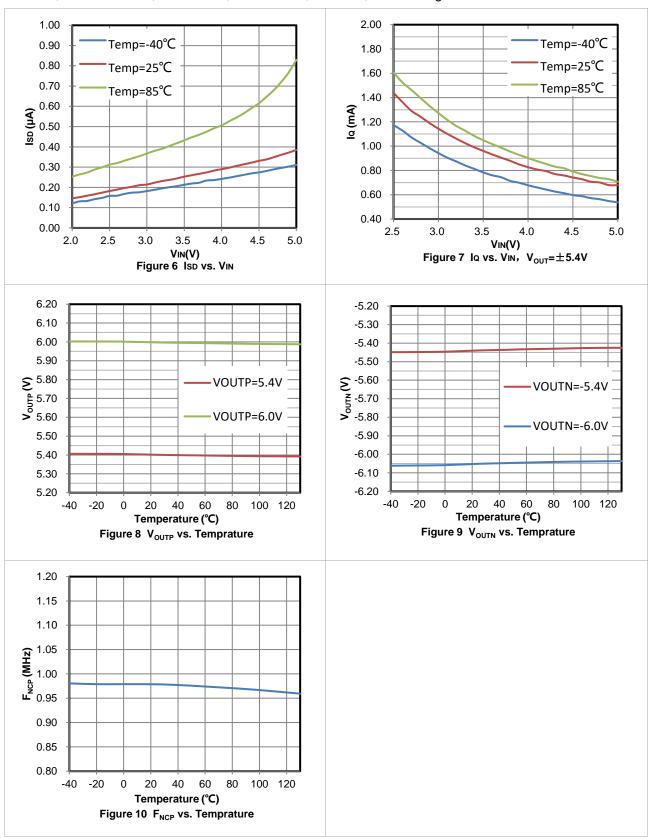


Figure 5 I²C Interface Timing

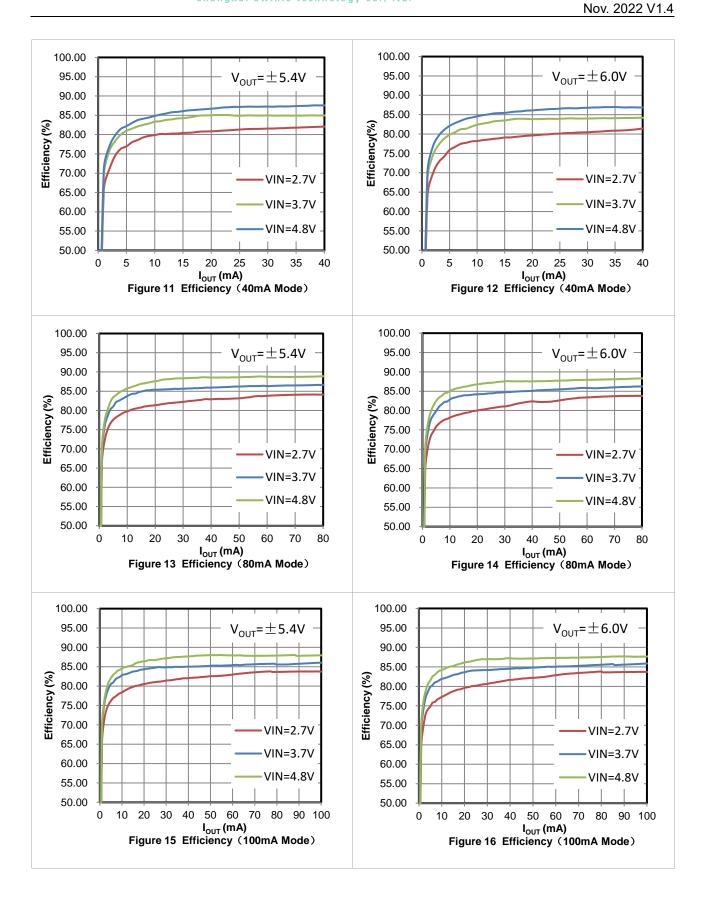


Typical Characteristics

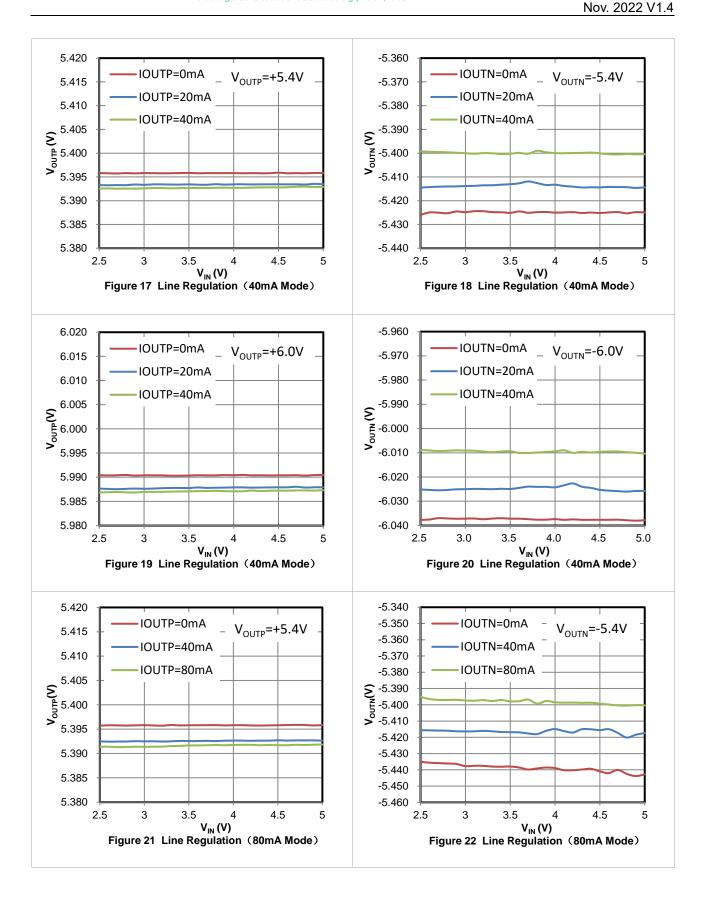
V_{IN}=3.7V, ENN=ENP=V_{IN}, V_{OUTP}=5.4V, V_{OUTN}=-5.4V, T_A=25°C, Circuit of figure 4 unless other noted.

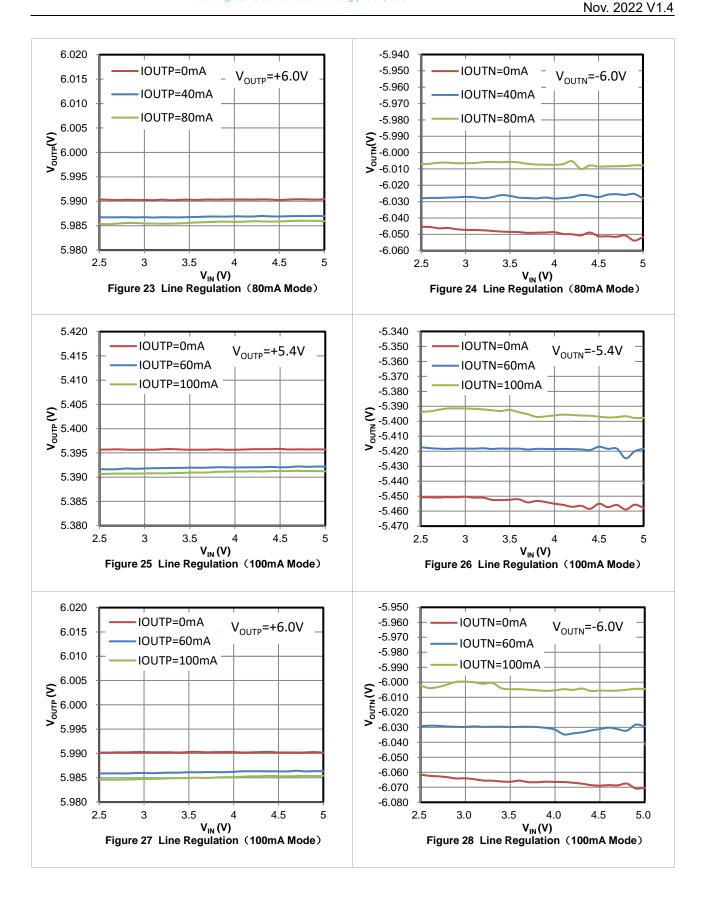




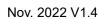


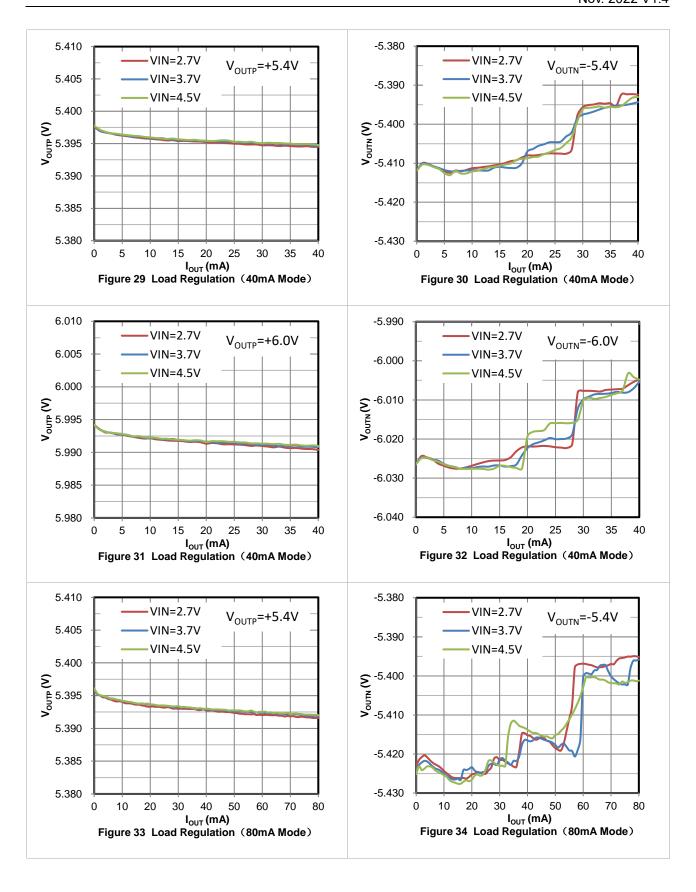






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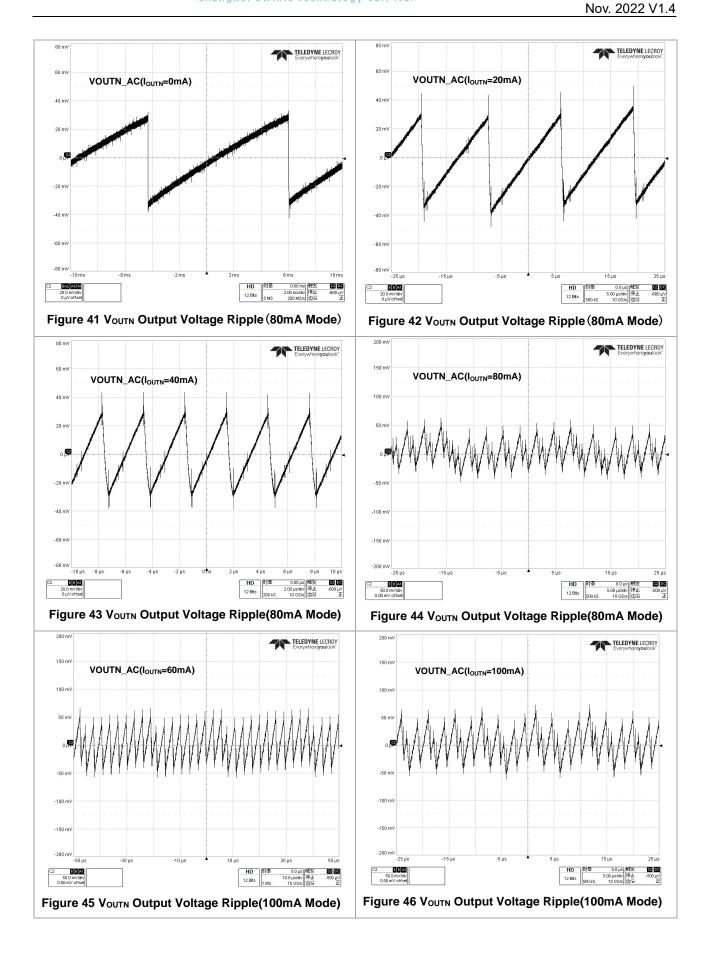






6.010 -5.990 VIN=2.7V VIN=2.7V V_{OUTP}=+6.0V V_{OUTN} =-6.0V 6.005 VIN=3.7V VIN=3.7V -6.000 VIN=4.5V VIN=4.5V 6.000 6.020 -6.020 5.995 5.990 -6.030 5.985 5.980 -6.040 10 20 40 50 60 70 40 70 80 10 50 60 I_{OUT} (mA) I_{OUT} (mA) Figure 35 Load Regulation (80mA Mode) Figure 36 Load Regulation (80mA Mode) 5.410 VIN=2.7V VIN=2.7V $V_{OUTP} = +5.4V$ -5.360 V_{OUTN}=-5.4V 5.405 VIN=3.7V VIN=3.7V VIN=4.5V VIN=4.5V -5.380 5.400 5.400 > 5.400 5.395 -5.420 5.390 -5.440 5.385 5.380 -5.460 40 50 60 70 80 90 100 10 20 30 10 20 40 50 60 70 80 90 100 30 I_{OUT} (mA) I_{OUT} (mA) Figure 37 Load Regulation (100mA Mode) Figure 38 Load Regulation (100mA Mode) 6.010 VIN=2.7V VIN=2.7V -5.980 V_{OUTP}=+6.0V V_{OUTN} =-6.0V 6.005 VIN=3.7V VIN=3.7V VIN=4.5V VIN=4.5V -6.000 6.000 -6.020 **S** -6.020 5.995 -6.040 5.990 -6.060 5.985 5.980 -6.080 40 50 60 70 80 90 100 10 20 30 40 50 60 70 80 90 100 10 20 30 I_{OUT} (mA) I_{OUT} (mA) Figure 40 Load Regulation (100mA Mode) Figure 39 Load Regulation (100mA Mode)

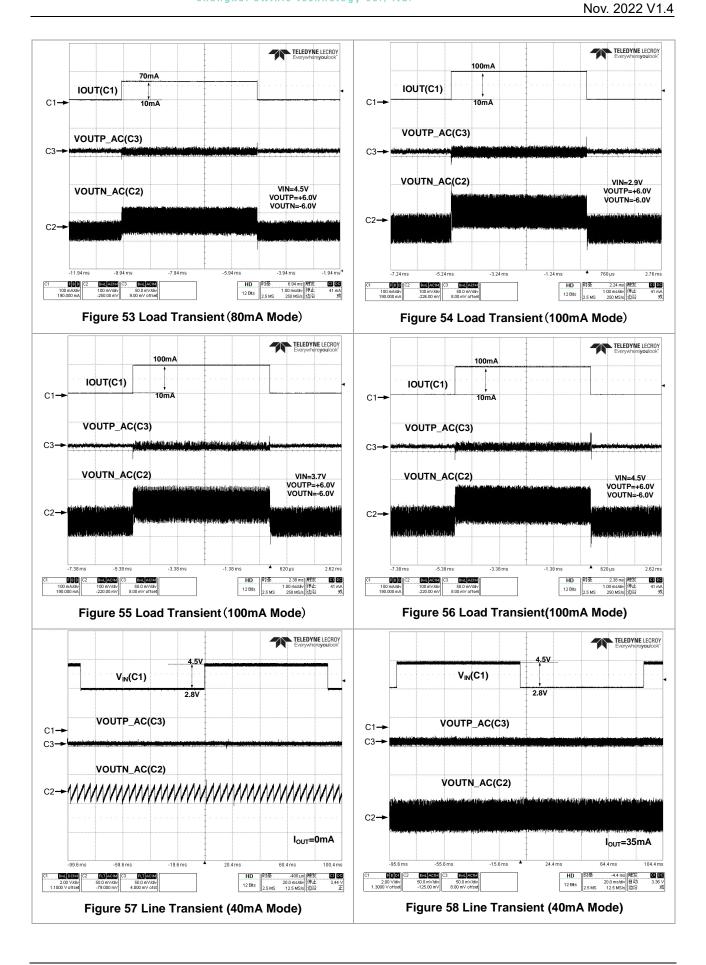




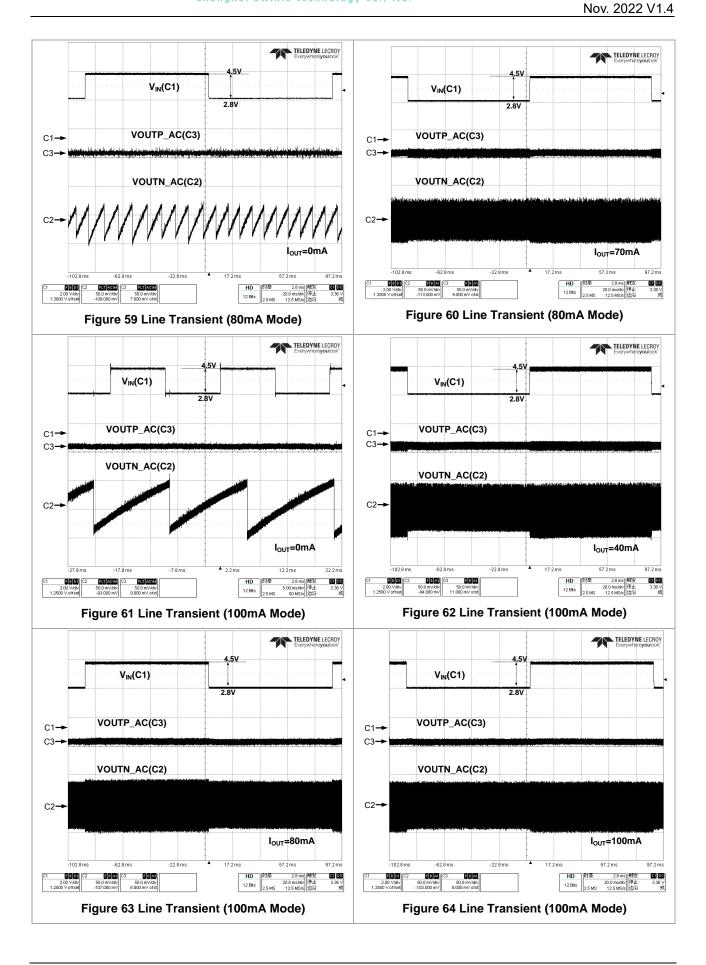


TELEDYNE LECROY 30 m 35mA VOUTP_AC(I_{OUTP}=150mA) IOUT(C1) C1 10 m\ VOUTP_AC(C3) VOUTN_AC(C2) C2-MMMMMMMM VIN=2.9V VOUTP=+6.0V VOUTN=-6.0V -30 m 662 µs -262 µs 338 115 HD 12 Bits 0 μs 開始 200 μs/div 停止 2.5 GS/s 边沿 Figure 47 Voutre Output Voltage Ripple Figure 48 Load Transient (40mA Mode) TELEDYNE LECROY TELEDYNE LECROY 35mA 35mA IOUT(C1) IOUT(C1) VOUTP_AC(C3) VOUTP_AC(C3) VOUTN_AC(C2) VOUTN_AC(C2) C2-WWWWW WAR VIN=3.7V VOUTP=+6.0V VOUTN=-6.0V VIN=4.5V 41.0 mA 41.0 mA Figure 50 Load Transient (40mA Mode) Figure 49 Load Transient (40mA Mode) TELEDYNE LECROY TELEDYNE LECROY 70mA IOUT(C1) IOUT(C1) C1 C1 VOUTP_AC(C3) VOUTP_AC(C3) VIN=2.9V VOUTP=+6.0V VOUTN=-6.0V VIN=3.7V VOUTP=+6.0V VOUTN=-6.0V VOUTN_AC(C2) VOUTN_AC(C2) 6.94 ms | 触发 1.00 ms/div 250 MS/s | 边沿 HD 时基 6.94 ms 解发 12.8tts 2.5 MS 250 MS/s 协治 41 mA Figure 51 Load Transient (80mA Mode) Figure 52 Load Transient (80mA Mode)

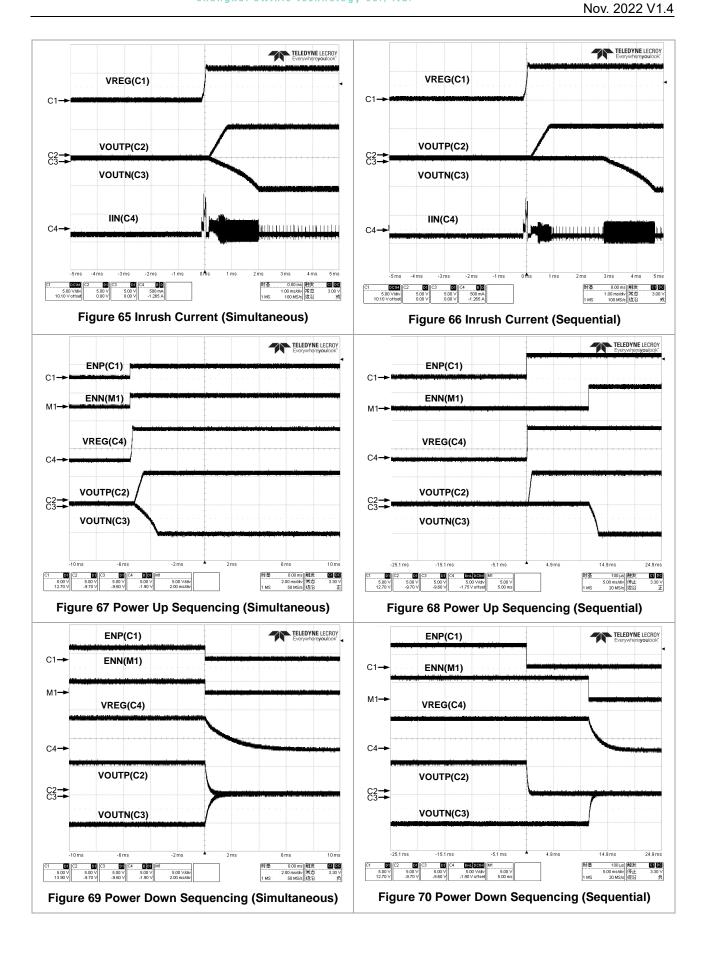




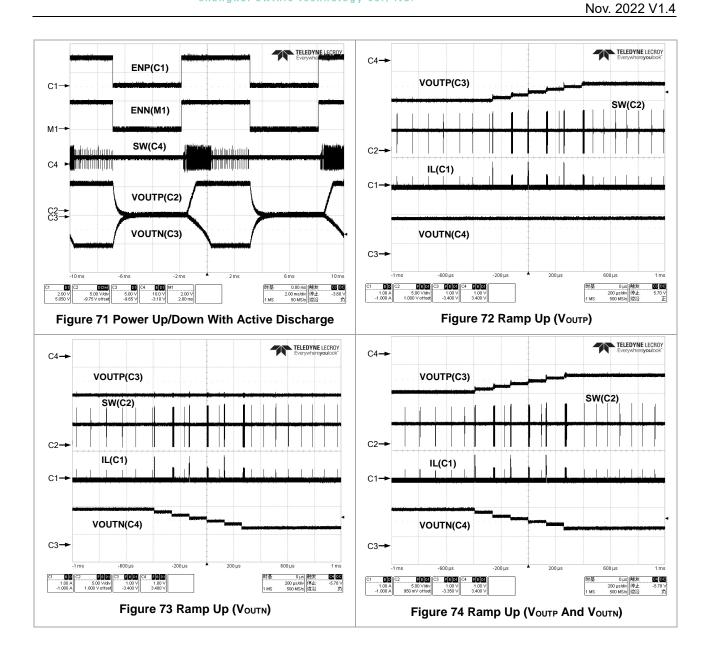














Detailed Functional Description

AW37501 is designed to generate both positive and negative bias voltages for TFT-LCD panels or other general dual power supply applications. It consists a highly integrated synchronous boost converter with input voltage range from 2.7V to 5.5V. An internal LDO drops down the output voltage of the boost converter (V_{REG}), delivering the positive supply from +4.0V to +6.0V (100mV/step). A charge pump inverts and regulates the output voltage of the boost converter (V_{REG}), providing the negative supply from -4.0V to -6.0V (100mV/step). The operating mode can be selected among 40mA, 80mA and 100mA in order to achieve the necessary current capability and to get the best efficiency performance based on the application.

Enabling and Disabling the Device

ENP and ENN separately control positive output(Voutp) and negative output (Voutn) enable or disable. When V_{IN} is above the UVLO threshold, ENP or ENN goes to a logic-high, the boost converter will start up firstly and then the positive or negative voltage output. The boost converter is turned off when both ENP and ENN are low or V_{IN} falls below the UVLO stop threshold. Both ENP pin and ENN pin have an internal 200kΩ pulldown resistance to ground.

Power-Up and Soft-Start

When V_{IN} is above UVLO threshold and ENN or ENP is pulled to high voltage, the boost converter is enabled. To avoid drawing high inrush current from a battery or high impedance power source during startup, the boost converter employs an internal soft-start feature.

During boost's soft start, inductance current is limited in two ways. When V_{REG} < 1.2V, the low side power transistor of boost is turned on for fixed on time and switching period, and the inductance current is DCM state; when $V_{REG} > 1.2V$, boost works in the low valley current limiting state; when V_{REG} reaches the target voltage, the boost converter has reached its power good, which means that boost output is established, soft start is finished, and LDO and charge pump are allowed to work after 60µs delay.

The LDO starts operating as soon as the ENP signal is pulled HIGH, when the boost converter has reached its power good threshold. The LDO integrates a soft-start that slowly ramps up its output voltage Voute regardless of the output capacitor and the target voltage, as long as the LDO current limit is not reached. the typical ramp-up time is 500µs.

The charge pump starts operating as soon as the ENN signal is pulled HIGH, when the boost converter has reached its power good threshold. The charge pump integrates a soft-start that slowly ramps up its output voltage V_{OUTN} regardless of the output capacitor and the target voltage, the charge pump current is limited and the limit current can be configured by REG03H[7:6].

The LDO and charge pump can be turn on via configuring REG03H[4:3] and REG21H, the REG21H is the written protect register of REG03H[4:3]. The detail function of REG03H[4:3] is descripted as below:

Power Control

REG03H[4]: ENN = Enable OUTN output. REG03H[3]: ENP = Enable OUTP output.

Note: Turning ON either the OUTP or OUTN output will also turn-on the boost converter for the REG voltage.

Power-Down and Discharge

The BOOST, LDO and NCP stop operating when V_{IN} goes down below the UVLO threshold (usually 2.2V) or when both ENP and ENN are pulled low. The LDO stops operating when only ENP is pulled down while boost and NCP can still work, the same as NCP when ENN is pulled down. Both OUTP and OUTN can be actively discharged to GND by setting controlling bits DISP and DISN of REG03H with an approximately 60Ω and 20Ω discharging resistor respectively. If programmed to be active, when the enable signals go low or V_{IN} falls below UVLO, the discharge will occur during power down.

AW37501

Nov. 2022 V1.4

Programmable OUTP and OUTN Voltage

The OUTP positive output voltage is generated from the LDO supplied from a synchronous Boost converter, and OUTP is set at a default value of 5.4V. The boost converter also drives an inverting charge pump to generate OUTN negative output voltage which is set at a default value of -5.4V. The dual output voltages can be respectively programmed via a I²C interface, and the available voltage ranges are from +4V to +6V for OUTP and from -4V to -6V for OUTN with 100mV per step.

BOOST Converter Output Voltage and Efficiency Improvement

The output voltage of boost is adjusted automatically based on the output voltages of LDO and charge pump. In order to achieve good efficiency and overall ripple effect, select the higher between Voutp and |Voutn|, and accumulate according to the current gear configuration. 200mV will be increased if 40mA or 80mA mode is configured; 300mV will be increased if 100mA mode is configured.

In 40mA or 80mA mode,

VREG = max (VOUTP, |VOUTN|) + 200 mV

In 100mA mode,

VREG = max (VOUTP, |VOUTN|) + 300 mV

In order to improve the efficiency, when boost works in DCM state, once the inductance current reaches 0A, it will enter the skip cycle mode and stop switching. When the output voltage is lower than the output regulation value, the switching will be restore again for realizing the constant voltage output. This mechanism can achieve the power saving effect under light load.

Under Voltage Lockout (UVLO)

To avoid the mistaken operation of the IC at low input voltage, an under voltage lockout is designed which shuts down the device at voltage lower than the typical UVLO threshold of 2.2V. A hysteresis of 200mV is added so that the device cannot be enabled again until the input voltage goes up to 2.4V. This hysteresis voltage avoids unusual shutdown due to broad line transients when the battery gets suddenly heavily loaded. The serial interface I²C is still functional in the UVLO stop condition and the I²C registers' contents is only reset under POR, which is lower than UVLO stop condition.

Overvoltage Protection

The output voltage of the boost converter (V_{REG}) is monitored with an overvoltage protection comparator, as soon as the OVP threshold of 7.3V is reached, the device stops switching. The device starts operation again once the output voltage falls 0.12V below the overvoltage threshold.

Over Current Protection

The AW37501 features a valley current limit sensing scheme to prevent from the BOOST is over loading. Current limit detection occurs during on-time of the synchronous rectifier cycle by cycle. When the inductor current is above the current limit within the whole switching cycle time, the off-time is increased to allow the inductor current to decrease to its threshold before the next on-time begins. When the current limit is reached, the output voltage V_{REG} will decreases if the load further increases. If V_{REG} is approximately below 1.2V during unexpected short circuit event, the boost converter works in discontinuous conduction mode to decrease the current from the battery. Once the short circuit event is released, the boost restarts.

The device also has an internal current limit circuit to help protect the LDO. During transient high-load current events, the OUTP sources a limited current of 370mA or 270mA, which is largely independent of the voltage at OUTP and can be configured via REG04H[4]. But if the output voltage of OUTP drops to 60% of the target value and over loading continues 32ms, this chip will shut down.



OUTN Output Current Limit

The OUTN built-in output current limit prevents the charge pump from over loading and OUTN short condition. The current limit threshold is decided by current mode set by REG03H[7:6].

Current mode	Current limit threshold
40mA mode	>40mA
80mA mode	>80mA
100mA mode	>100mA

Thermal Shutdown

The device has a built-in temperature sensor which monitors the internal junction temperature. When the junction temperature exceeds 140°C, IC shuts down. When the junction temperature falls below the thermal recovery temperature, approximately 120 °C, the device restarts by using the soft-start sequence.



General I²C Operation

The device supports the I²C serial bus and data transmission protocol. It operates as a slave on the I²C bus. The maximum clock frequency specified by the I²C standard is 400kHz. Connect to the bus are made via the open-drain I/O pins SCL and SDA. The pull-up resistor can be selected in the range of $1k\sim10k\Omega$ and the typical value is $4.7k\Omega$ when I²C frequency is 400kHz. Different high level from 1.2V to 5V of this I²C interface is supported.

Device Address

AW37501 7-bit slave address (A7~A1) is 0111110 binary(0x3EH). After the START condition, the I^2C master sends the 7-bit chip address followed by an eighth (A0) read or write bit (R/W). R/W= 0 indicates a WRITE function and R/W = 1 indicates a READ function.

Table 5. Device Address

A7	,	A6	A5	A4	A3	A2	A1	A0
0		1	1	1	1	1	0	R/W

I²C Start/Stop

I²C start: SDA changes from high level to low level when SCL is high level.

I²C stop: SDA changes from low level to high level when SCL is high level.

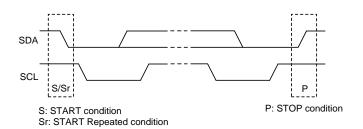


Figure 75 I²C Start/Stop Condition Timing

Data Validation

When SCL is high level, SDA level must be constant. SDA can be changed only when SCL is low level.

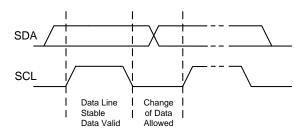


Figure 76 Data Validation Diagram



ACK (Acknowledgement)

ACK means the successful transfer of I²C bus data. After master sends an 8-bit data, SDA must be released; SDA is pulled to GND by slave device when slave acknowledges.

When master reads, slave device sends 8-bit data, releases the SDA and waits for ACK from master. If ACK is send and I²C stop is not send by master, slave device sends the next data. If ACK is not send by master, slave device stops to send data and waits for I²C stop.

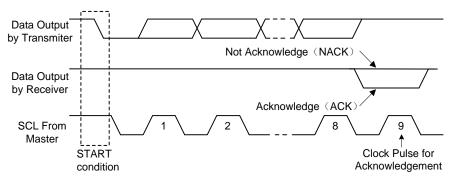


Figure 77 I²C ACK Timing

Write Cycle

One data bit is transferred during each clock pulse. Data is sampled during the high state of the serial clock (SCL). Consequently, throughout the clock's high period, the data should remain stable. Any changes on the SDA line during the high state of the SCL and in the middle of a transaction, aborts the current transaction. New data should be sent during the low SCL state. This protocol allows a single data line to transfer both command/control information and data using the synchronous serial clock.

Each data transaction is composed of a start condition, a number of byte transfers (set by the software) and a stop condition to terminate the transaction. Every byte written to the SDA bus must be 8 bits long and is transferred with the most significant bit first. After each byte, an Acknowledge signal must follow.

In a write process, the following steps should be followed:

- Master device generates START condition. The "START" signal is generated by lowering the SDA signal while the SCL signal is high.
- b) Master device sends slave address (7-bit) and the data direction bit (R/W = 0).
- c) Slave device sends acknowledge signal if the slave address is correct.
- d) Master sends control register address (8-bit)
- e) Slave sends acknowledge signal
- f) Master sends data byte to be written to the addressed register
- g) Slave sends acknowledge signal
- h) If master will send further data bytes, the control register address will be incremented by one after acknowledge signal (repeat step f and g)
- i) Master generates STOP condition to indicate write cycle end



Figure 78 I²C Write Byte Cycle



Read Cycle

In a read cycle, the following steps should be followed:

- a) Master device generates START condition
- b) Master device sends slave address (7-bit) and the data direction bit (R/W = 0).
- c) Slave device sends acknowledge signal if the slave address is correct.
- d) Master sends control register address (8-bit)
- e) Slave sends acknowledge signal
- f) Master generates STOP condition followed with START condition or REPEAT START condition
- g) Master device sends slave address (7-bit) and the data direction bit (R/W = 1).
- h) Slave device sends acknowledge signal if the slave address is correct.
- i) Slave sends data byte from addressed register.
- j) If the master device sends acknowledge signal, the slave device will increase the control register address by one, then send the next data from the new addressed register.
- k) If the master device generates STOP condition, the read cycle is ended.

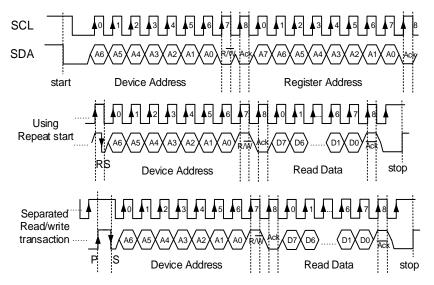


Figure 79 I²C Read Byte Cycle



Register Configuration

Register MAP

ADDR	NAME	R/W	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	Default					
0x00	VOUTP	R/W			VOUTP[4:0]				0x0E							
0x01	VOUTN	R/W	RSVD[2:0]				VOUTN[4:0]					VOUTN[4:0]				0x0E
0x03	APPS	R/W	APPS	S[1:0]	RESET	ENN	ENP	RSVD	DISP	DISN	0x43					
0x04	CTRL	R/W	RSVD[2:0] ILMTLDO RSVD VENDOR[1:0]				0x01									
0x21	WPRTEN	R/W		Written protect functional Register							0x00					

R/W = Read/Write.

Register Detailed Description

VOUTP: VOUTP Configure Register(Address 00H)

Bit	Symbol	R/W		Description						
7:5	RSVD[2:0]	R	Reserved.							
			Output voltage of	of LDO						
			VOUTP[4:0]	VOUTP(V)	VOUTP[4:0]	VOUTP(V)				
			00000	4.0	01011	5.1				
			00001	4.1	01100	5.2				
			00010	4.2	01101	5.3				
			00011	4.3	01110	5.4(default)	00			
4:0	VOUTP[4:0]	RW	00100	4.4	01111	5.5	0x0E			
			00101	4.5	10000	5.6	1			
			00110	4.6	10001	5.7	1			
			00111	4.7	10010	5.8				
			01000	4.8	10011	5.9	1			
			01001	4.9	10100	6.0				
			01010	5.0			1			

VOUTN: VOUTN Configure Register(Address 01H)

Bit	Symbol	R/W		Description					
7:5	RSVD[2:0]	R	Reserved.	Reserved.					
			Output voltage of						
			VOUTN[4:0]	VOUTN(V)	VOUTN[4:0]	VOUTN(V)			
			00000	-4.0	01011	-5.1			
			00001	-4.1	01100	-5.2			
			00010	-4.2	01101	-5.3			
			00011	-4.3	01110	-5.4(default)	005		
4:0	VOUTN[4:0]	RW	00100	-4.4	01111	-5.5	0x0E		
			00101	-4.5	10000	-5.6	- -		
			00110	-4.6	10001	-5.7			
			00111	-4.7	10010	-5.8			
			01000	-4.8	10011	-5.9			
			01001	-4.9	10100	-6.0			
			01010	-5.0					



APPS: Applications Configure Register(Address 03H)

Bit	Symbol	R/W	Description	Default
7			Current mode application.	
6	6 APPS[1:0]		00: 40mA mode; 01: 80mA mode(default).10: 100mA mode; 11: 100mA mode.	
5	RESET	R/W Soft reset bit. 0: keep; Write 1: reset.		
4	ENN	R/W	Enable charge pump output. It must be written after writing the register 0x21H=4CH; 0: disable (default); 1: enable.	0x43
3	ENP	R/W	Enable LDO output. It must be written after writing the register 0x21H=4CH; 0: disable (default); 1: enable.	
2	RSVD	R/W	R/W Reserved.	
1	DISP I R/W I		LDO actively discharge enable. 0:disable; 1:enable (default).	
0	DISN	R/W	Charge pump actively discharge enable. 0:disable; 1:enable (default).	

CTRL: Control State Configure Register(Address 04H)

Bit	Symbol	R/W	Description	Default
7:5	RSVD[2:0]	R	Reserved.	
4	ILMTLDO	R/W	LDO output current limit value configure: 0: 370mA(default); 1: 270mA.	0,01
3:2	RSVD[1:0]	R	Reserved.	0x01
1:0	VENDOR[1:0]	R	Vendor ID, read only. 01: AWINIC Vendor Number(default). 00,10,11: others.	

WPRTEN: Written Protect Functional Register(Address 21H)

Bit	Symbol	R/W	Description	Default
7:0	WPRTEN	W/R	Write protect functional register of APPS[4:2]: Write 4CH open written protect function, and read, return 01H; Write other codes to disable writing register of APPS[4:2], and return 00H when read;	0x00

Application Information

The AW37501 employs a single inductor scheme to support positive /negative supply at current up to 100mA. Below are some peripheral selection guidelines.

The first step in the design procedure is to verify whether the maximum possible output current of the boost converter supports the specific application requirement. A simple approach is to estimate the converter efficiency, by taking the efficiency number from the provided efficiency curves at the application's maximum load or to use a worst case assumption for the expected efficiency.

1. Duty cycle:

$$D = 1 - \frac{V_{IN} - \min \times \eta}{V_{RFG}} \tag{1}$$

Inductor ripple current:

$$\Delta I_L = \frac{V_{IN} - \min \times D}{f_{SW} \times L} \tag{2}$$

Maximum output current:

$$IOUT _max = \left(ILIM _min + \frac{\Delta IL}{2}\right)(1 - D)$$
 (3)

Peak switch current of the application:

$$I_{\text{SWPEAK}} = \frac{I_{\text{OUT}}}{1 - D} + \frac{\Delta I_{\text{L}}}{2}$$
 (4)

 η = Estimated boost converter efficiency (use the number from the efficiency plots or 85% as an estimation)

f_{SW} = Boost converter switching frequency

L = Selected inductor value for the boost converter

 I_{SWPEAK} = Boost converter switch current at the desired output current (must be < [I_{LIM_min} + ΔI_L])

ΔI_L = Inductor peak-to-peak ripple current

V_{REG} = max (V_{OUTP}, V_{OUTN}) + 200mV (in 40mA mode or 80 mA mode) or + 300mV (in 100mA mode)

I_{OUT} = I_{OUT_VOUTP} + |I_{OUT_VOUTN}|, (I_{OUT_max} being the maximum current delivered on each rail)

The peak switch current is the current that the integrated switch and the inductor have to handle. The calculation must be done for the minimum input voltage where the peak switch current is highest.

The AW37501 integrates a charge pump to support negative supply. The charge pump uses only two external capacitors C4 and C5 as shown in the Figure 1. The output characteristics of this charge pump can be approximated by an ideal voltage source in series with a resistor. The voltage source equals -V_{REG}. The output resistance Rout is a function of the ON resistance of the internal MOS switches, the oscillator frequency, and the capacitance and ESR of C4 and C5. A good approximation is:

$$Rout = 2 \times Rsw + \frac{1}{F_{NCP} \times C_4} + 4ESR_{C4} + ESR_{C5}$$
 (5)

Where Rsw is the ON resistance of the internal MOS switches. High value, low ESR capacitors reduce the output resistance. The littler of the distance from C4 to CFLY1/2 in the PCB layout can also reduce the output resistance. Instead of increasing the capacitance, the oscillator frequency can be increased to reduce the 2/(F_{NCP}*C₄) term. Once this term is trivial compared with R_{SW} and ESRs, further increase to oscillator frequency and capacitance become ineffective. Furthermore larger oscillator frequency can increase quiescent current. The peak to peak output voltage ripple is determined by the oscillator frequency, and the capacitance and ESR of the output capacitor C5:



 $V_{\text{ripple}} = \frac{I_{\text{OUTN}}}{F_{\text{OSC}} \times C_5} + 2 \times I_{\text{OUTN}} \times ESR \text{ cs}$ (6)

Again, using a low ESR capacitor results in lower ripple.

The output resistance and ripple voltage are dependent on the capacitance and ESR values of the external capacitors. The output voltage drop from V_{RGE} to -V_{OUTN} is the load current times the output resistance, and the charge pump efficiency is shown by:

$$\eta = \frac{\mathsf{Pout}}{\mathsf{P}_{\mathsf{IN}}} = \frac{\left(\mathsf{Ioutn}\,\right)^2 \mathsf{RL}}{\left(\mathsf{Ioutn}\,\right)^2 \mathsf{RL} + \left(\mathsf{Ioutn}\,\right)^2 \mathsf{Rout} + \mathsf{Iq}(\mathsf{NCP})} \tag{7}$$

where

I_{Q(NCP)} is the quiescent power loss of the charge pump

(Ioutn)²Rout is the conversion loss associated with the switch on resistance, the two external capacitors and their ESRs.

Inductor Selection

Saturation current: the inductor must handle the maximum peak current {IL sat > Iswpeak, or IL sat > [ILIM min $+\Delta I_L$] as conservation approach}.

DC Resistance: the lower the DCR, the lower the losses. Inductor value: in order to keep the ratio I_{OUT}/ΔI_L low enough for proper sensing operation purpose, it is recommended to use a 4.7µH inductor for 40mA mode (a 2.2µH might however be used, but the efficiency might be lower than with 4.7µH at light loads depending on the inductor characteristics).

L(µH)	Supplier	Component Code	ELA Size	I _{SAT} (A)	DCR TYP(mΩ)
2.2	Toko	1269AS-H-2R2N=P2	1008	2.4	130
2.2	Chilisin	MHCD252012A-2R2M-A8S	2520	2	102
4.7	Toko	1269AS-H-4R7N=P2	1008	1.6	250
4.7	Sunlord	WPN252010HS4R7MT	2520	1.3	276

Capacitor Selection

For best input voltage filtering low ESR ceramic capacitors are recommended for input capacitors. The AW37501 has an analog input pin VIN. A 4.7μF minimum bypass capacitor is required as closed as possible from VIN to GND. For better input voltage filtering, this value can be increased or two capacitors can be used. For output capacitors, higher capacitors values can be used to improve the load transient response and reduce output voltage ripple. For the best output voltage filtering, low ESR ceramic capacitors are recommended. A minimum of 4.7µF ceramic output capacitors is required. The NCP needs an external flying capacitor. The minimum value is 2.2µF. For proper operation, the flying capacitor value must be lower than the output capacitor of the boost converter on REG pin.

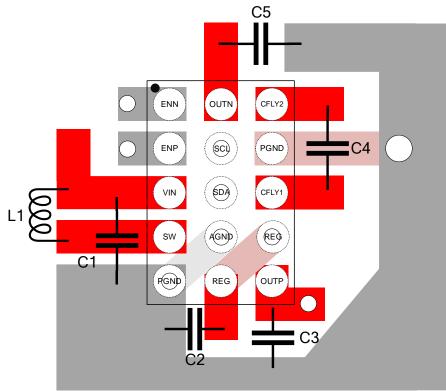
Capacitor(µF)	Supplier	Component Code	ELA Size	Voltage Rating(V)	Comments
2.2	Murata	GRM188R61C225KAAD	0603	16	C _{FL} Y
4.7	Murata	GRM188R61C475KAAJ	0603	16	CIN, COUTN, CFLY, COUTP, CREG
10	Murata	GRM219R61C106KA73	0603	16	C _{OUTN} , C _{OUTP} , C _{REG}



PCB Layout Consideration

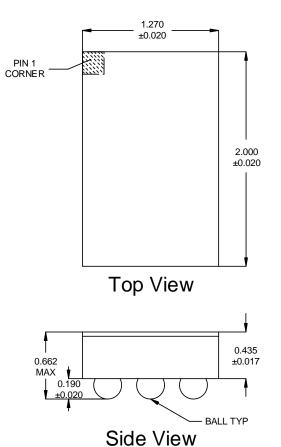
AW37501 is a single inductor and dual outputs power supple, to obtain the optimal performance, PCB layout should be considered carefully. Here are some guidelines:

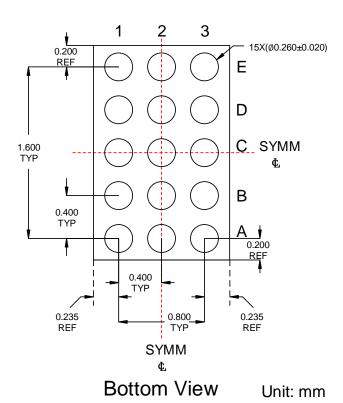
- 1. All peripheral components should be placed as close to the chip as possible. C1 C2 C3 C4 C5 and L1 should be close to VIN、REG、OUTP、CFLY1/2 and OUTN pins respectively. Avoid to connect device and chip pins with two different layers of copper, use the same layer of copper instead.
- 2. VIN and SW are the large current input of the chip, please routed according to 2.5A rule, and the advised width is 100mil.
- 3. The connection lines between the planes of C1、C2、C3、C4、C5 and respective chip pins should be as short and wide as possible, to reduce noise and ripple.
- 4. The exposed plane of chip and GND pins must be connected to the large-area ground layer of PCB directly, meanwhile place sufficient via below the exposed plane. Thus we can decrease the thermal resistor on the board to optimize heat-diffusion performance.
- To achieve optimal large-current performance, the power path shown in red as the figure below must be widen.



Via to signal layer on internal or bottom layer.

Package Description

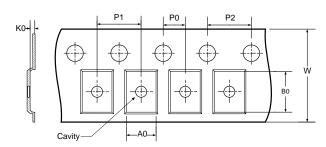




Tape And Reel Information

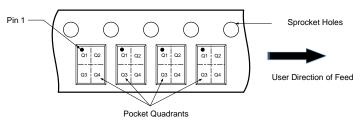
REEL DIMENSIONS D1 0

TAPE DIMENSIONS



- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- K0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
 P0: Pitch between successive cavity centers and sprocket hole
- P1: Pitch between successive cavity centers
- P2: Pitch between sprocket hole
- D1: Reel Diameter
- D0: Reel Width

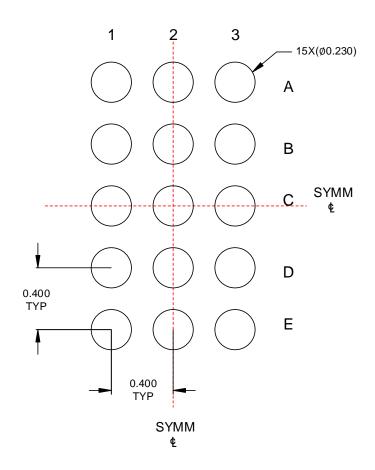
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

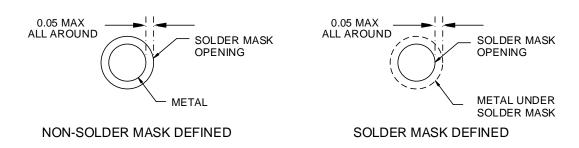


All Dimensions are nominal

D1 (mm)	D0 (mm)	A0 (mm)		_	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
179.00	9.00	1.40	2.10	0.76	2.00	4.00	4.00	8.00	Q1

Land Pattern Data





UNIT: mm



Revision History

Version	Date	Change Record
V1.0	Sep. 2020	Official released
V1.1	Apr. 2021	 Changed V_{OUTP} and V_{OUTN} default output condition: amend I_{OUT}=40mA to I_{OUT}=80mA (Page 6) Added V_{OUTP} line variation and V_{OUTN} line variation to Electrical Characteristics table (Page 6 and Page 7) Modified the line regulation of V_{OUTP} and V_{OUTN} (Page 6 and Page 7) Revised figure 71 (Page 20) Fixed some formatting and syntax errors
V1.2 Jun. 2021		 Add the range of parameters in Electrical Characteristics (Page 6 and Page 7) Add Application Information (Page 29 and Page 30)
V1.3	Oct. 2021	 Changed the input voltage rang "2.7V to 5.0V" to "2.7V to 5.5V" Added V_{IH}, V_{IL} and V_{OL} parameters of SDA and SCL ports in EC table Deleted the ENSTB description in register 0x03[2], and change it to RSVD Fixed the molecular numerical error for the second item of formula (5).



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